

AM0608-450

PRELIMINARY DATA

RF & MICROWAVE TRANSISTORS AVIONICS APPLICATIONS

REFRACTORY/GOLD METALLIZATION

- INPUT MATCHING
- OVERLAY GEOMETRY
- METAL/CERAMIC HERMETIC PACKAGE
- \blacksquare Pout = 445 W MIN. WITH 6.9 dB GAIN





DESCRIPTION

The AM0608-450 is an internally-matched, common base silicon bipolar device optimized pulsed application in the 600 - 750 MHz frequency range.

Housed in the industry-standard BIGPAC[™] metal/ceramic package, this device uses a refractory/gold overlay die geometry for ruggedness and long-term reliability.

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^{\circ}C$)

Symbol	Parameter	Value	Unit	
P _{DISS}	Power Dissipation* $(T_C \le 50^{\circ}C)$	1500	W	
Ic	Device Current* 32			
Vcc	Collector-Supply Voltage*	55	V	
TJ	Junction Temperature (Pulsed RF Operation) 250		°C	
T _{STG}	Storage Temperature	– 65 to +200	°C	

THERMAL DATA

R _{TH(j-c)}	Junction-Case Thermal Resistance*	0.13	°C/W

*Applies only to rated RF amplifier operation

AM0608-450

ELECTRICAL SPECIFICATIONS $(T_{case} = 25^{\circ}C)$

STATIC

			Value			
Symbol		Test Conditions	Min.	Тур.	Max.	Unit
ВУсво	$I_C = 50 \text{mA}$	$I_E = 0mA$	65	—	_	V
BVEBO	$I_E = 5mA$	$I_{C} = 0mA$	3.5	_	—	V
BVCER	IC = 50mA	$R_{BE} = 10\Omega$	65	_		V
ICES	$V_{CE} = 50V$				35	mA
I _{CBO}	$V_{CB} = 50V$			_	25	mA
h _{FE}	$V_{CE} = 5V$	$I_{C} = 1A$	15	_	300	—

DYNAMIC

				Value			
Symbol		Test Conditions		Min.	Тур.	Max.	Unit
Роит	f = 600 — 750MHz	$P_{IN} = 90W$	$V_{CC} = 50V$	445	—	_	W
ηc	f = 600 — 750MHz	$P_{IN} = 90W$	$V_{CC} = 50V$	35	—		%
GP	f = 600 — 750MHz	$P_{IN} = 90W$	$V_{CC} = 50V$	6.9	—		dB

Note: Pulse Width = 10μ S

Duty Cycle = 1%

TEST CIRCUIT

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PACKAGE MECHANICAL DATA



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